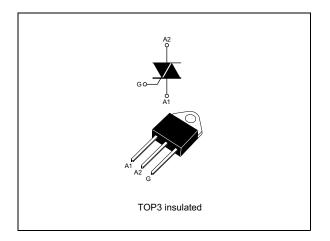


# **TPDVxx40**

## 40 A high voltage Triacs

#### Datasheet - production data



### Features

- On-state current (I<sub>T(RMS)</sub>): 40 A
- Max. blocking voltage (V<sub>DRM</sub>/V<sub>RRM</sub>): 1200 V
- Gate current (I<sub>GT</sub>): 200 mA
- Commutation at 10 V/µs: up to 142 A/ms
- Noise immunity: 500 V/µs
- Insulated package:
  - 2,500 V rms (UL recognized: E81734)

### Description

The TPDVxx40 series use a high performance alternistor technology. Featuring very high commutation levels and high surge current capability, this family is well adapted to power control on inductive load (motor, transformer...).

| Parameter  | Blocking<br>voltage<br>V <sub>DRM</sub> /V <sub>RRM</sub> | On-state<br>current<br>I <sub>T(RMS)</sub> | Gate<br>current<br>I <sub>GT</sub> |
|------------|---|--|------------------------------------|
| TPDV640RG  | 600 V   |  |                                    |
| TPDV840RG  | 800 V   | 40 A                                       | 200 mA                             |
| TPDV1240RG | 1200 V  |  |                                    |

This is information on a product in full production.

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# 1 Characteristics

| Symbol                               | Paramete   | Value                   | Unit                    |             |                  |
|--------------------------------------|--|-------------------------|-------------------------|-------------|------------------|
| I <sub>T(RMS)</sub>                  | On-state rms current (180° conduction angle) $T_c = 75 \degree C$                                  |                         |                         | 40          | А                |
|                                      |  | t <sub>p</sub> = 2.5 ms |                         | 590         | А                |
| I <sub>TSM</sub>                     | Non repetitive surge peak on-state current   | t <sub>p</sub> = 8.3 ms | T <sub>j</sub> = 25 °C  | 370         |                  |
|                                      |  | t <sub>p</sub> = 10 ms  |                         | 350         |                  |
| l <sup>2</sup> t                     | I <sup>2</sup> t value for fusing  | t <sub>p</sub> = 10 ms  | T <sub>j</sub> = 25 °C  | 610         | A <sup>2</sup> S |
| di/dt                                | Critical rate of rise of on-state current<br>I <sub>G</sub> = 500 mA; dI <sub>G</sub> /dt = 1 A/µs | Repetitive F =          | Repetitive F = 50 Hz    |             | A/µs             |
| dl/dt                                |  | Non repetitive          | Non repetitive          |             |                  |
|                                      |  | TPDV640                 | T <sub>j</sub> = 125 °C | 600         | v                |
| V <sub>DRM</sub><br>V <sub>RRM</sub> | Repetitive peak off-state voltage  | TPDV840                 |                         | 800         |                  |
| . KKIN                               |  | TPDV1240                |                         | 1200        |                  |
| T <sub>stg</sub>                     | Storage junction temperature range   |                         |                         | -40 to +150 | °C               |
| Tj                                   | Operating junction temperature range   |                         |                         |             | 0                |
| ΤL                                   | Maximum lead temperature for soldering   | 260                     | °C                      |             |                  |
| V <sub>INS(RMS)</sub> <sup>(1)</sup> | Insulation rms voltage   | Insulation rms voltage  |                         |             |                  |

| Table 2 | Absolute | ratings | (limitina    | values) |  |
|---------|----------|---------|--------------|---------|--|
|         | Absolute | ratings | (initiality) | values  |  |

1. A1, A2, gate terminals to case for 1 minute

### Table 3. Electrical Characteristics ( $T_j = 25$ °C, unless otherwise specified)

| Symbol                         | Test condition   |  | Quadrant     |        | Value | Unit     |
|--------------------------------|--|--|--------------|--------|-------|----------|
| I <sub>GT</sub>                | V <sub>D</sub> = 12 V DC, R <sub>I</sub> = 33 Ω                              |  | -    -       | Max.   | 200   | mA       |
| V <sub>GT</sub>                | $v_{\rm D} = 12 v DC, R_{\rm L} = 33 \Omega$                                 |  | 1 - 11 - 111 | Max.   | 1.5   | V        |
| V <sub>GD</sub>                | $V_D = V_{DRM} R_L = 3.3 k\Omega$  | T <sub>j</sub> = 125 °C                        | -    -       | Min.   | 0.2   | V        |
| t <sub>gt</sub>                | $V_D = V_{DRM} I_G = 500 \text{ mA } dI_G/dt =$                              | 3A/µs  | -    -       | Тур.   | 2.5   | μs       |
| I <sub>H</sub> <sup>(1)</sup>  | I <sub>T</sub> = 500 mA Gate open  |  |              | Тур.   | 50    | mA       |
| 1                              | 4.0 %  |  | -            | Тур.   | 100   | mA       |
| IL IL                          | IG - I.2 X IGT   | $I_{G} = 1.2 \times I_{GT}$                    |              |        | 200   |          |
| dV/dt                          | Linear slope up to :<br>$V_D = 67\% V_{DRM}$ Gate open $T_j = 125 \degree C$ |  |              | Min.   | 500   | V/µs     |
| V <sub>TM</sub> <sup>(1)</sup> | I <sub>TM</sub> = 56 A t <sub>p</sub> = 380 μs                               | I <sub>TM</sub> = 56 A t <sub>p</sub> = 380 μs |              | Max.   | 1.8   | V        |
| I <sub>DRM</sub>               | $T_j = 25 \text{ °C}$  |  |              | Max.   | 20    | μA       |
| I <sub>RRM</sub>               | V <sub>DRM =</sub> V <sub>RRM</sub>  | T <sub>j</sub> = 125 °C                        |              | ινιαλ. | 8     | mA       |
| (dl/dt)c <sup>(1)</sup>        | (dV/dt)c = 200 V/µs  |  |              | N dire | 35    | A //20 0 |
|                                | (dV/dt)c = 10 V/µs   | T <sub>j</sub> = 125 °C                        |              | Min.   | 142   | A/ms     |

1. For either polarity of electrode  $A_2$  voltage with reference to electrode  $A_1$ .

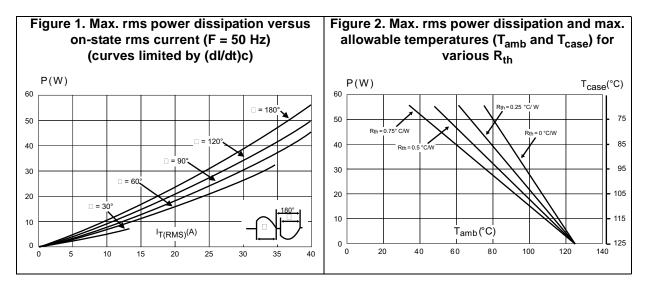


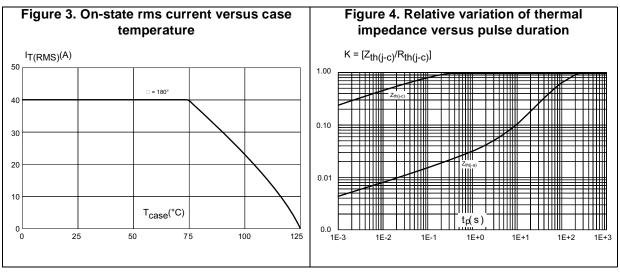
| Symbol             | Parameter   | Parameter                                |    | Unit |  |
|--------------------|---|--|----|------|--|
| P <sub>G(AV)</sub> | Average gate power dissipation                    |  | 1  | W    |  |
| P <sub>GM</sub>    | Peak gate power dissipation $t_p = 20 \ \mu s$    |  | 40 | W    |  |
| I <sub>GM</sub>    | Peak gate current                                 | Peak gate current t <sub>p</sub> = 20 µs |    | A    |  |
| V <sub>GM</sub>    | Peak positive gate voltage t <sub>p</sub> = 20 µs |  | 16 | V    |  |

Table 4. Gate characteristics (maximum values)

### Table 5. Thermal resistance

| Symbol                  | Parameter  | Value | Unit |
|-------------------------|--|-------|------|
| R <sub>th(j-a)</sub>    | Junction to ambient                                    | 50    | °C/W |
| R <sub>th(j-c)</sub> DC | Junction to case for DC                                | 1.2   | °C/W |
| R <sub>th(j-c)</sub> AC | Junction to case for 360 °conduction angle (F = 50 Hz) | 0.9   | °C/W |





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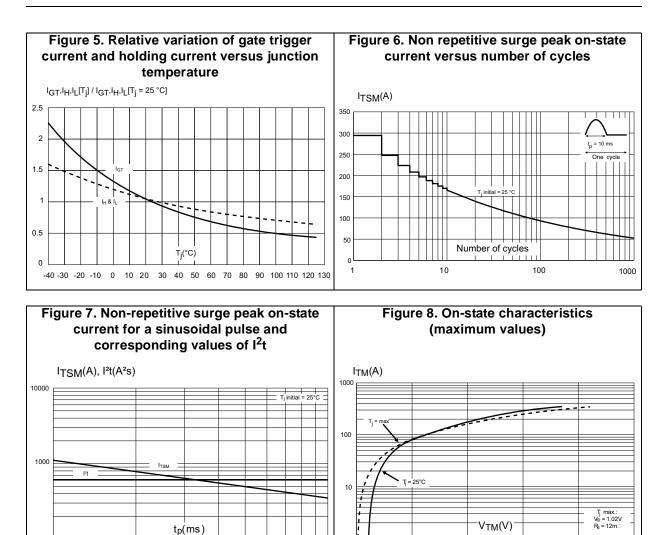
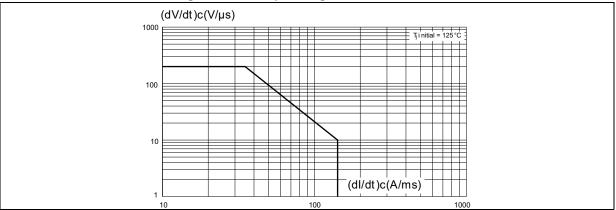


Figure 9. Safe operating area below curve



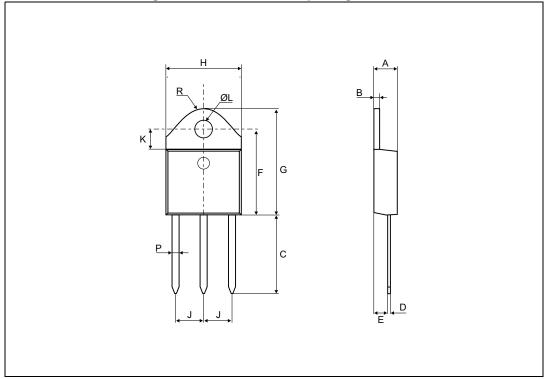


## 2 Package information

- Epoxy meets UL94, V0
- Cooling method:C (by conduction)
- Recommended torque value:0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

## 2.1 TOP3 insulated package information



#### Figure 10. TOP3 insulated package outline



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|      | Dimensions |             |       |       |                       |       |
|------|------------|-------------|-------|-------|-----------------------|-------|
| Ref. |            | Millimeters |       |       | Inches <sup>(1)</sup> |       |
|      | Тур.       | Min.        | Max.  | Тур.  | Min.                  | Max.  |
| А    |            | 4.4         | 4.6   |       | 0.173                 | 0.181 |
| В    |            | 1.45        | 1.55  |       | 0.057                 | 0.061 |
| С    |            | 14.35       | 15.60 |       | 0.565                 | 0.614 |
| D    |            | 0.5         | 0.7   |       | 0.020                 | 0.028 |
| Е    |            | 2.7         | 2.9   |       | 0.106                 | 0.114 |
| F    |            | 15.8        | 16.5  |       | 0.622                 | 0.650 |
| G    |            | 20.4        | 21.1  |       | 0.815                 | 0.831 |
| Н    |            | 15.1        | 15.5  |       | 0.594                 | 0.610 |
| J    |            | 5.4         | 5.65  |       | 0.213                 | 0.222 |
| К    |            | 3.4         | 3.65  |       | 0.134                 | 0.144 |
| ØL   |            | 4.08        | 4.17  |       | 0.161                 | 0.164 |
| Р    |            | 1.20        | 1.40  |       | 0.047                 | 0.055 |
| R    | 4.60       |             |       | 0.181 |                       |       |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

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# **3** Ordering information

| Order code | Marking  | Package           | Weight | Base qty. | delivery mode |  |
|------------|----------|-------------------|--------|-----------|---------------|--|
| TPDV640RG  | TPDV640  |                   |        |           |               |  |
| TPDV840RG  | TPDV840  | TOP3<br>insulated | 4.5 g  | 30        | Tube          |  |
| TPDV1240RG | TPDV1240 |                   |        |           |               |  |

Table 7. Ordering information

## 4 Revision history

| Date        | Revision | Changes  |
|-------------|----------|--|
| 30-Mar-2011 | 1        | Initial release.   |
| 10-Jun-2015 | 2        | Updated <i>Table 3</i> .<br>Updated <i>Figure 9</i> .<br>Format updated to current standard. |

### Table 8. Document revision history



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